PSPICE

What is Spice?

- Spice is the short form of:
 - Simulated
 - Program with
 - Integrated
 - Circuit
 - Emphasis

PSPICE Programming

- Why PSPICE Programming
- Steps of Programming
- Statements
- Data Statements
- Control Statements
- Example Circuits

Why PSPICE Programming

- Don't have to draw the circuit
- More control over the parts
- More control over the analysis
- Don't have to search for parts
- Some SPICE software (HSPICE etc.) don't have GUI at all
- Quick and efficient

Steps of Programming

- Draw the circuit and label the nodes
- Create net list (*.cir) file
- Add in control statements
- Add in title, comment & end statements
- Run PSPICE
- Evaluate the results of the output

Statements

Different statements:

- Not case sensitive
- title first line of code or keep Blank (always)
- .end last line of code (always)
- Comment: line denoted by *
- Data: resistor, capacitor, etc.
- Control: analysis and output

Resistor

- R<name><node1><node2><value>
- Example: R1 1 2 100

Capacitor

- C<name><node1><node2><value>
- Example: C1 13 0 1u

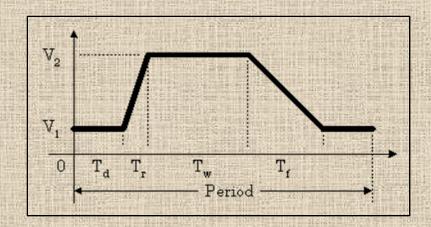
Inductor

- L<name><node1><node2><value>
- Example: L1 5 4 1m

- Independent Voltage Source
 - V<name><+ node><- node> [[DC] <value>] [AC <magnitude> [phase]] [transient + specification]
- 3 types of sources:
 - DC: Vin 105
 - AC: Va 4 0 AC 25
 - Transient

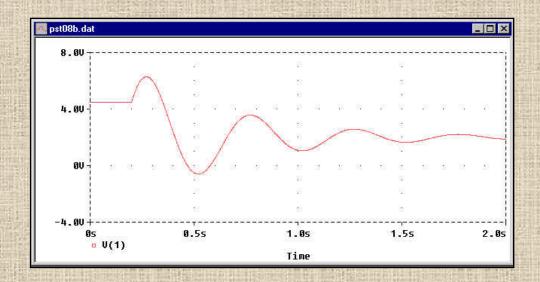
Transient Source

- vname <n+><n-> pulse(V1 V2 Td Tr Tf Tw Period)
- Example 1: va 2 0 pulse(5 0 0 1p 1p 10n 20n)
- Example 2: vb 3 0 pulse(5 0 0 1p 1p 5n 10n)



Transient Source

- vname <n+> <n-> sin(Vo Va freq td phase)
- vname <n+> <n-> pwl(t1,v1,t2,v2,...,tn,vn)



- Independent Current Source
- Same as Independent Voltage Source

MOSFET

- m<name><drain><gate><source><substrate><mo del>[W=<value>][L=<value>]
- .model <name><NMOS or PMOS>[params]

• Example:

- mp1 4 2 1 1 ptype w=5u l=2.5u
- mn1 5 2 0 0 ntype w=5u l=5u
- .model ptype PMOS(VTO=-1V KP=15u)
- .model ntype NMOS(VTO=1V KP=30u)

Suffixes

f	femto	10-15
р	pico	10 ⁻¹²
n	nano	10-9
u i i i i i i i i i i i i i i i i i i i	micro	10-6
m	milli	10 ⁻³
k	kilo	10 ³
meg	mega	106
g	giga	109
t	tera	10 ¹²

Control Statements

- Analysis Types
 - DC Analysis: .dc
 - AC Analysis: .ac
 - Transient Analysis: .tran
- Output Format
 - Text Output: .print, .plot
 - Graph Output: .probe

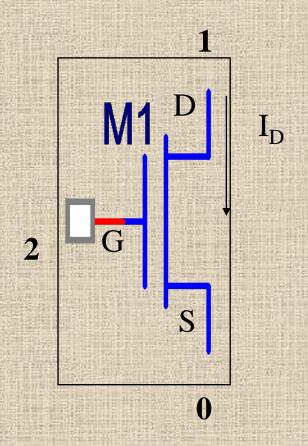
DC Analysis

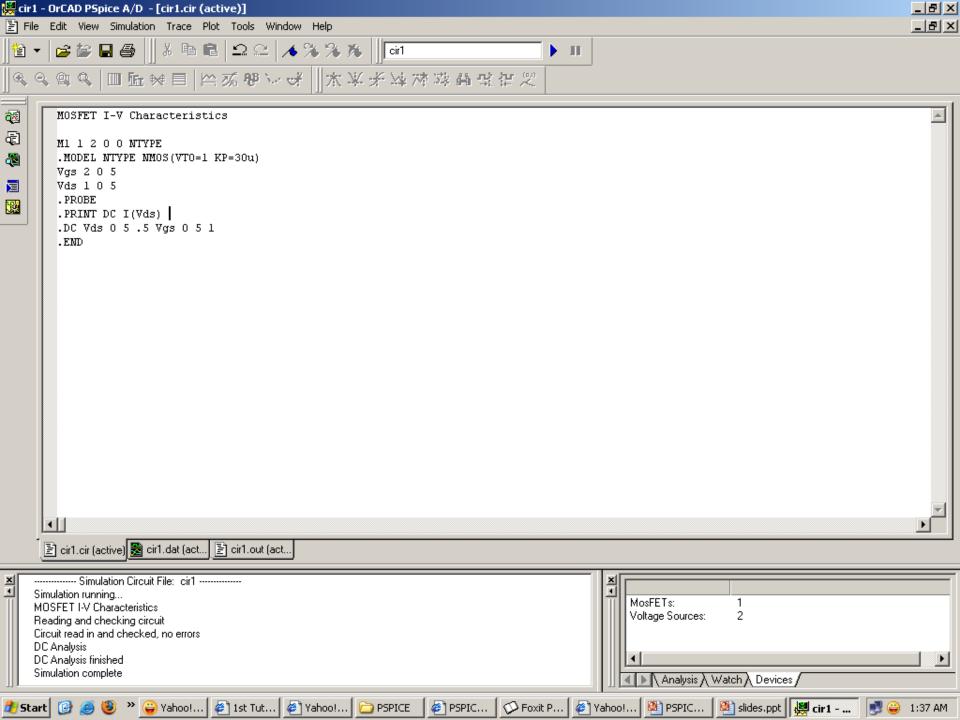
- Format
 - .dc <source> <vstart> <vstop> <vincr> [src2 start2 stop2 incr2]
- Example:
 - .dc Vin 0.25 5.0 0.25
 - -. dc Vds 0 10 0.5 Vgs 0 5 1

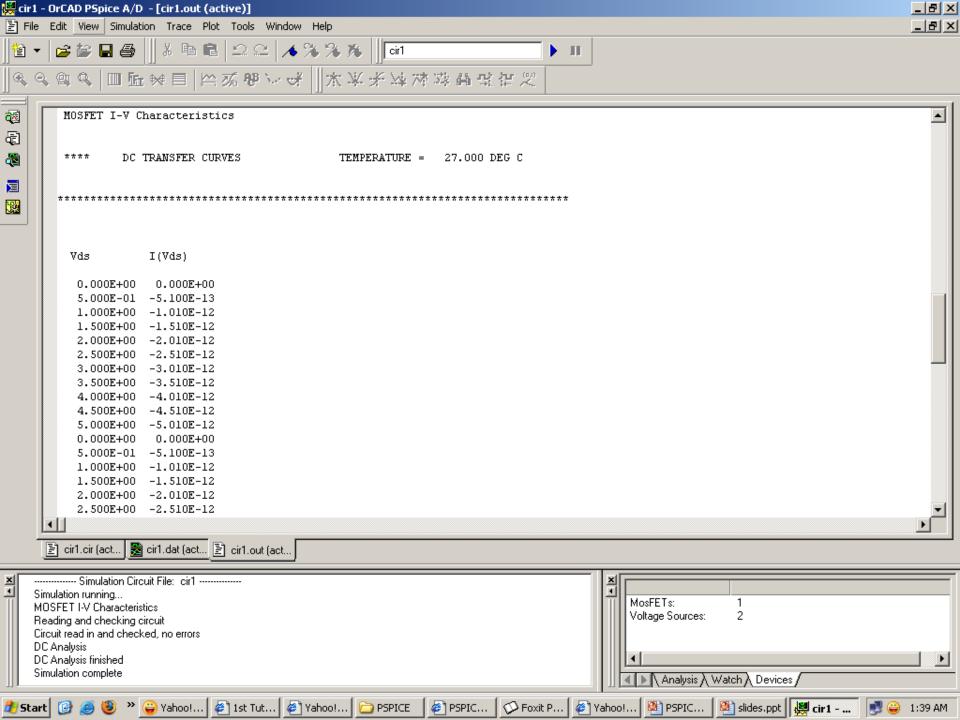
DC Analysis

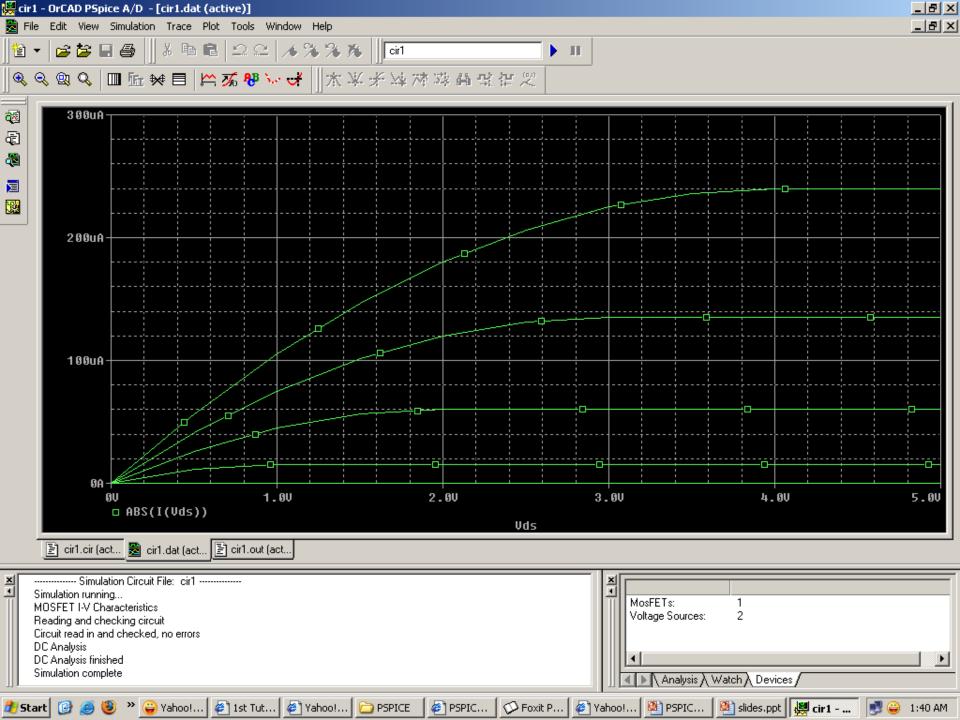
Plot I-V Characteristics of NMOS

m1 1 2 0 0 ntype .model ntype NMOS(vto=1 kp=30u) vqs 205 vds 105 .probe .print dc i(vds) .dc vds 0 5 .5 vgs 0 5 1 .end









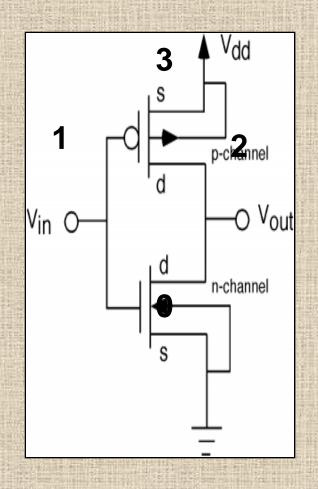
Transient Analysis

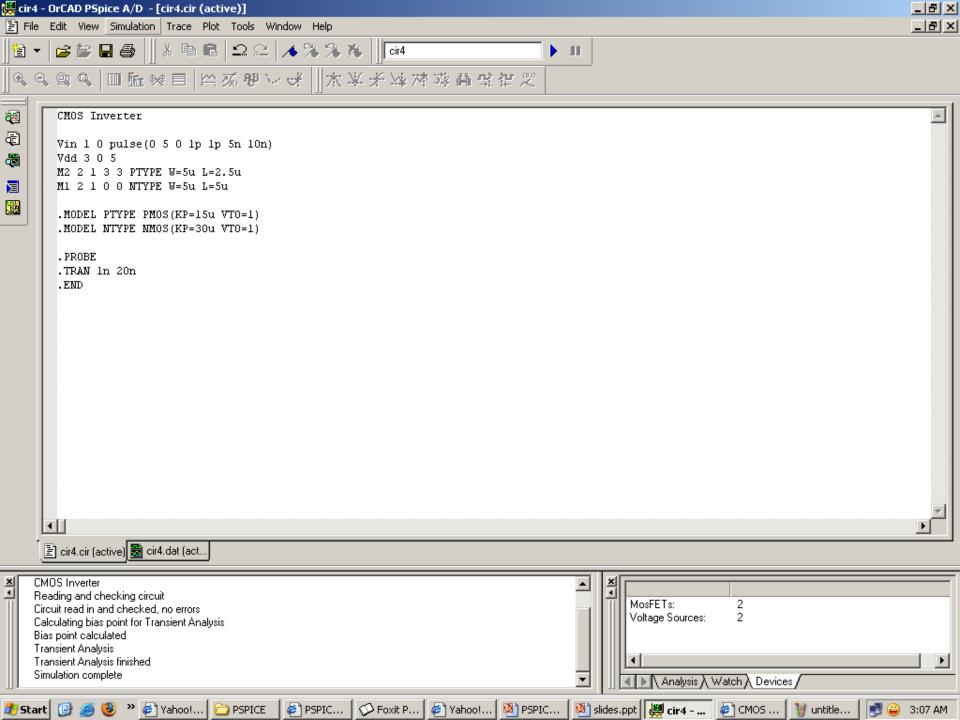
- Format
 - .tran <print step><final time>
- Example
 - .tran 1n 1000n

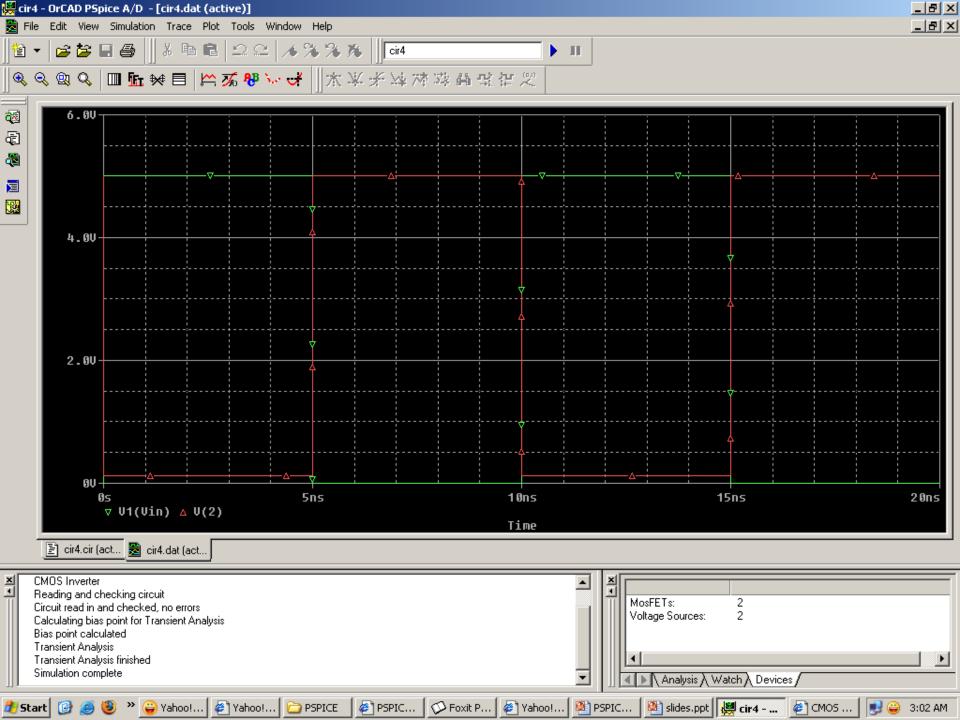
Transient Analysis

CMOS Inverter

vin 1 0 pulse(0 5 0 1p 1p 5n 10n) vdd 3 0 5 m2 2 1 3 3 ptype w=5u l=2.5u m1 2 1 0 0 ntype w=5u l=5u .model ptype PMOS(kp=15u vto=-1) .model ntype NMOS(kp=30u vto=1) .probe .tran 1n 20n .end





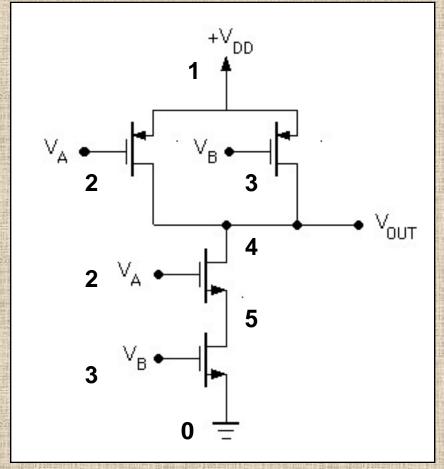


CMOS NAND

mp1 4 2 1 1 p w=5u l=2.5u mp2 4 3 1 1 p w=5u l=2.5u mn1 4 2 5 0 n w=5u l=5u mn2 5 3 0 0 n w=5u l=5u .model p PMOS(VTO=-1 KP=15u) .model n NMOS(VTO=1 KP=30u) vin1 2 0 pulse(0 5 0 1n 1n 5u 10u) vin2 3 0 pulse(0 5 2.5u 1n 1n 5u 10u) vp 105 .probe

.tran 0 30u .1u

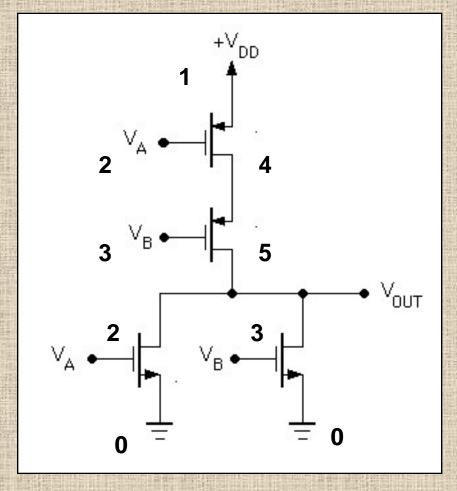
.end



CMOS NOR

mp1 4 2 1 1 p w=5u l=2.5u mp2 5 3 4 1 p w=5u l=2.5u mn1 5 2 0 0 n w=5u l=5u mn2 5 3 0 0 n w=5u l=5u .model p PMOS(VTO=-1 KP=15u) .model n NMOS(VTO=1 KP=30u) vin1 2 0 pulse(0 5 0 1n 1n 5u 10u) vin2 3 0 pulse(0 5 2.5u 1n 1n 5u 10u) vp 105 .probe .tran 0 30u .1u

.end



Sub Circuit

.subckt sub1 5 12 18

Iw 10 12 10A

Ra 5 12 5.0

Rb 5 13 4.0

Rc 12 13 2.0

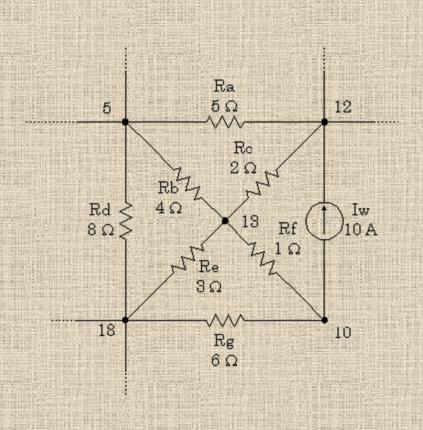
Rd 5 18 8.0

Re 13 18 3.0

Rf 10 13 1.0

Rg 10 18 6.0

.ends



Sub Circuit

.include sub1.cir

Vs1 0 50

Iq 5 0 15

Ra 121

Rb 3 4 3

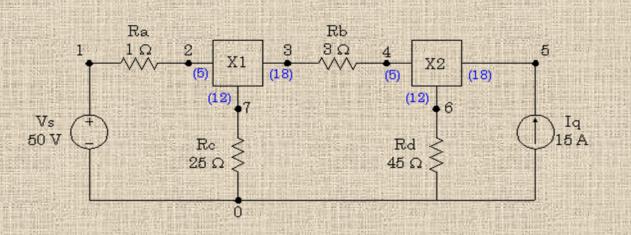
Rc7 0 25

Rd 6 0 45

X1 2 7 3 sub1

X2 4 6 5 sub1

.end



Thanks